



0.5W Zener Diode - 1N52*B series

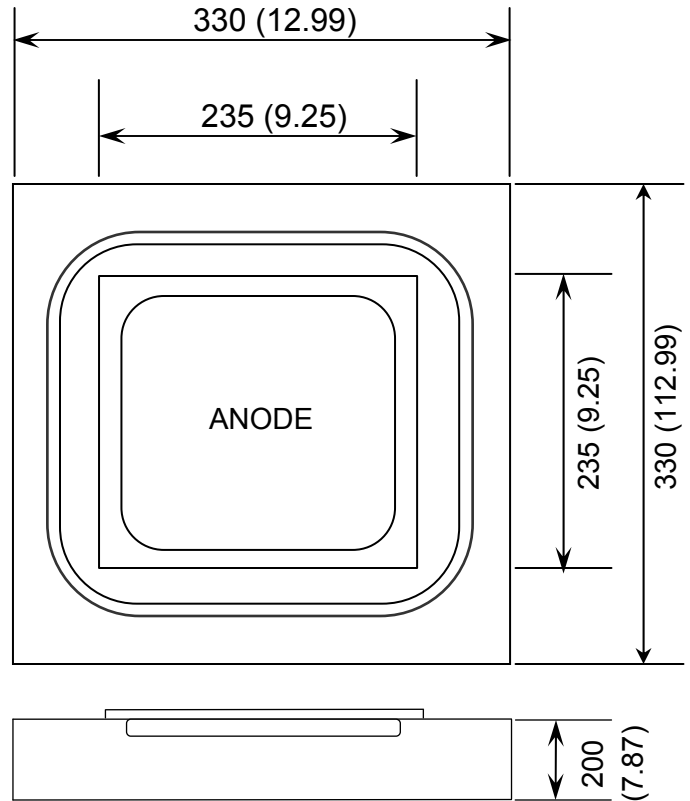
Rev 1.1
05/04/19

Silicon Planar Zener diode in bare die form – 5% tolerance

Features:

- Sharp Reverse Characteristics
- Low Reverse Current Levels
- High Reliability Gold Back Metal
- High Reliability tested grades.

Die Dimensions in μm (mils)



CHIP BACKSIDE IS CATHODE

Ordering Information

The following part suffixes apply:

- No suffix - Commercial grade die
- “H” – Hi-rel grade die + MIL-STD-38534 Class H LAT
- “K” – Hi-rel grade die + MIL-STD-38534 Class K LAT.

LAT = Lot acceptance Test.

For information on Hi-Rel LAT flows please see below.

www.siliconsupplies.com/bare-die-lot-qualification

Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape – By specific request
- Unsawn Wafer – By specific request
- With additional electrical selection – By specific request

Mechanical Specification

| | | |
|------------------------|----------------------------|-----------------------|
| Die Size (Unsawn) | 330 x 330 12.99 x 12.99 | μm mils |
| Anode Pad Size | 235 x 235 9.25 x 9.25 | μm mils |
| Die Thickness | 200 7.87 | μm mils |
| Top Metal Composition | Al | |
| Back Metal Composition | AuAs | |





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Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise stated

| PARAMETER | SYMBOL | VALUE | UNIT |
|--|-----------|-------------|------------------|
| Power Dissipation | P_{TOT} | 500 | mW |
| Junction Temperature | T_J | 175 | $^\circ\text{C}$ |
| Storage Temperature Range | T_S | -65 to +200 | $^\circ\text{C}$ |
| Forward Voltage @ $I_F = 200\text{mA}$ | V_F | 1.5 | V |

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise stated

| DEVICE | ZENER VOLTAGE RANGE | | | TEST CURRENT | | REVERSE LEAKAGE CURRENT | | DYNAMIC RESISTANCE | | TEMP. COEFFICIENT |
|---------|---------------------|------|-------|--------------|-----------|-------------------------|-----|--------------------|--------------------|-------------------|
| | $V_Z @ I_{ZT1}$ | | | I_{ZT2} | I_{ZT2} | $I_R @ V_R$ | | $Z_Z @ I_{ZT1}$ | $Z_{ZK} @ I_{ZT2}$ | αV_Z |
| | V | | | mA | | μA | V | Ω | | %/K |
| | Min. | Nom. | Max. | | | Max. | | Max. | Max. | Typ. |
| 1N5221B | 2.28 | 2.4 | 2.52 | 20 | 0.25 | 100 | 1 | 30 | 1200 | -0.085 |
| 1N5222B | 2.38 | 2.5 | 2.63 | 20 | 0.25 | 100 | 1 | 30 | 1250 | -0.085 |
| 1N5223B | 2.57 | 2.7 | 2.84 | 20 | 0.25 | 75 | 1 | 30 | 1300 | -0.08 |
| 1N5224B | 2.66 | 2.8 | 2.94 | 20 | 0.25 | 75 | 1 | 30 | 1400 | -0.08 |
| 1N5225B | 2.85 | 3 | 3.15 | 20 | 0.25 | 50 | 1 | 29 | 1600 | -0.075 |
| 1N5226B | 3.14 | 3.3 | 3.47 | 20 | 0.25 | 25 | 1 | 28 | 1600 | -0.07 |
| 1N5227B | 3.42 | 3.6 | 3.78 | 20 | 0.25 | 15 | 1 | 24 | 1700 | -0.065 |
| 1N5228B | 3.71 | 3.9 | 4.10 | 20 | 0.25 | 10 | 1 | 23 | 1900 | -0.06 |
| 1N5229B | 4.09 | 4.3 | 4.52 | 20 | 0.25 | 5 | 1 | 22 | 2000 | 0.055 |
| 1N5230B | 4.47 | 4.7 | 4.94 | 20 | 0.25 | 5 | 1 | 19 | 1900 | 0.03 |
| 1N5231B | 4.85 | 5.1 | 5.36 | 20 | 0.25 | 5 | 2 | 17 | 1600 | 0.03 |
| 1N5232B | 5.32 | 5.6 | 5.88 | 20 | 0.25 | 5 | 3 | 11 | 1600 | 0.038 |
| 1N5233B | 5.70 | 6 | 6.30 | 20 | 0.25 | 5 | 3.5 | 7 | 1600 | 0.038 |
| 1N5234B | 5.89 | 6.2 | 6.51 | 20 | 0.25 | 5 | 4.0 | 7 | 1000 | 0.045 |
| 1N5235B | 6.46 | 6.8 | 7.14 | 20 | 0.25 | 3 | 5.0 | 5 | 750 | 0.05 |
| 1N5236B | 7.13 | 7.5 | 7.88 | 20 | 0.25 | 3 | 6.0 | 6 | 500 | 0.058 |
| 1N5237B | 7.79 | 8.2 | 8.61 | 20 | 0.25 | 3 | 6.5 | 8 | 500 | 0.062 |
| 1N5238B | 8.27 | 8.7 | 9.14 | 20 | 0.25 | 3 | 6.5 | 8 | 600 | 0.065 |
| 1N5239B | 8.65 | 9.1 | 9.56 | 20 | 0.25 | 3 | 7.0 | 10 | 600 | 0.068 |
| 1N5240B | 9.50 | 10 | 10.50 | 20 | 0.25 | 3 | 8.0 | 17 | 600 | 0.075 |
| 1N5241B | 10.45 | 11 | 11.55 | 20 | 0.25 | 2 | 8.4 | 22 | 600 | 0.076 |
| 1N5242B | 11.40 | 12 | 12.60 | 20 | 0.25 | 0.1 | 9.1 | 30 | 600 | 0.077 |
| 1N5243B | 12.35 | 13 | 13.65 | 9.5 | 0.25 | 0.1 | 9.9 | 13 | 600 | 0.079 |
| 1N5244B | 13.30 | 14 | 14.70 | 9.0 | 0.25 | 0.1 | 10 | 15 | 600 | 0.082 |





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|---------|---------------------|------|-------|--------------|-----------|-------------------------|----|--------------------|--------------------|-------------------|
| | $V_Z @ I_{ZT1}$ | | | I_{ZT2} | I_{ZT2} | $I_R @ V_R$ | | $Z_Z @ I_{ZT1}$ | $Z_{ZK} @ I_{ZT2}$ | αV_Z |
| | V | | | mA | | μA | V | Ω | | %/K |
| | Min. | Nom. | Max. | | | Max. | | Max. | Max. | Typ. |
| 1N5245B | 14.25 | 15 | 15.75 | 8.5 | 0.25 | 0.1 | 11 | 19 | 600 | 0.082 |
| 1N5246B | 15.20 | 16 | 16.80 | 7.8 | 0.25 | 0.1 | 12 | 21 | 600 | 0.083 |
| 1N5247B | 16.15 | 17 | 17.85 | 7.4 | 0.25 | 0.1 | 13 | 23 | 600 | 0.084 |
| 1N5248B | 17.1 | 18 | 18.90 | 7 | 0.25 | 0.1 | 14 | 25 | 600 | 0.085 |
| 1N5249B | 18.05 | 19 | 19.95 | 6.6 | 0.25 | 0.1 | 14 | 29 | 600 | 0.086 |
| 1N5250B | 19 | 20 | 21.00 | 6.2 | 0.25 | 0.1 | 15 | 33 | 600 | 0.086 |
| 1N5251B | 20.9 | 22 | 23.10 | 5.6 | 0.25 | 0.1 | 17 | 35 | 600 | 0.087 |
| 1N5252B | 22.8 | 24 | 25.20 | 5.2 | 0.25 | 0.1 | 18 | 41 | 600 | 0.088 |
| 1N5253B | 23.75 | 25 | 26.25 | 5 | 0.25 | 0.1 | 19 | 44 | 600 | 0.089 |
| 1N5254B | 25.65 | 27 | 28.35 | 4.6 | 0.25 | 0.1 | 21 | 49 | 600 | 0.09 |
| 1N5255B | 26.6 | 28 | 29.40 | 4.5 | 0.25 | 0.1 | 21 | 58 | 600 | 0.091 |
| 1N5256B | 28.5 | 30 | 31.50 | 4.2 | 0.25 | 0.1 | 23 | 70 | 600 | 0.091 |
| 1N5257B | 31.35 | 33 | 34.65 | 3.8 | 0.25 | 0.1 | 25 | 80 | 700 | 0.092 |
| 1N5258B | 34.2 | 36 | 37.80 | 3.4 | 0.25 | 0.1 | 27 | 93 | 700 | 0.093 |
| 1N5259B | 37.05 | 39 | 40.95 | 3.2 | 0.25 | 0.1 | 30 | 105 | 800 | 0.094 |
| 1N5260B | 40.85 | 43 | 45.15 | 3 | 0.25 | 0.1 | 33 | 125 | 900 | 0.095 |
| 1N5261B | 44.65 | 47 | 49.35 | 2.7 | 0.25 | 0.1 | 36 | 150 | 1000 | 0.095 |
| 1N5262B | 48.45 | 51 | 53.55 | 2.5 | 0.25 | 0.1 | 39 | 170 | 1100 | 0.096 |
| 1N5263B | 53.2 | 56 | 58.80 | 2.2 | 0.25 | 0.1 | 43 | 185 | 1300 | 0.096 |
| 1N5264B | 57 | 60 | 63.00 | 2.1 | 0.25 | 0.1 | 46 | 230 | 1400 | 0.097 |
| 1N5265B | 58.9 | 62 | 65.10 | 2 | 0.25 | 0.1 | 47 | 270 | 1400 | 0.097 |
| 1N5266B | 64.6 | 68 | 71.40 | 1.8 | 0.25 | 0.1 | 52 | 330 | 1600 | 0.097 |
| 1N5267B | 71.25 | 75 | 78.75 | 1.7 | 0.25 | 0.1 | 56 | 370 | 1700 | 0.098 |

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.
2. Assembled in DO-35 package. Performance in die form subject to assembly heat sinking and die attach methods.





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Zener Impedance Versus Operating Current - Z_z Versus I_z

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